

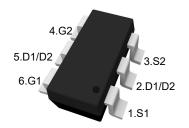
# TN&\$\$+8 BG;

# **Dual N-Channel Enhancement Mode Power MOSFET**

### **Features**

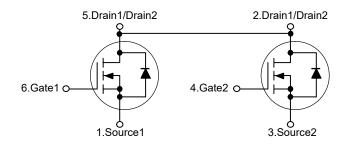
- Excellent R<sub>DS(on)</sub> and low gate charge
- Lead free product is acquired
- High Power and Current handing capability
- V<sub>DS</sub>= 20V,I<sub>D</sub>= 6.5A
   R<sub>DS</sub>(on)< 28mΩ @V<sub>GS</sub>= 4.5V

### SOT-23-6



Marking Code: 2007

### **Schematic Diagram**



### **Absolute Maximum Ratings**

Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter                  | Symbol           | Value       | Unit |
|----------------------------|------------------|-------------|------|
| Drain-Source Voltage       | V <sub>DS</sub>  | 20          | V    |
| Gate-Source Voltage        | V <sub>GS</sub>  | ±12         | V    |
| Drain Current-Continuous   | I <sub>D</sub>   | 6.5         | А    |
| Drain Current-Pulsed Note1 | I <sub>DM</sub>  | 20          | Α    |
| Maximum Power Dissipation  | P <sub>D</sub>   | 1.2         | W    |
| Junction Temperature       | TJ               | 150         | °C   |
| Storage Temperature Range  | T <sub>STG</sub> | -55 to +150 | °C   |

### **Thermal Characteristics**

| Thermal Resistance,Junction-to-Ambient Note2 | R <sub>θJA</sub> | 104 | °C/W |
|--|------------------|-----|------|
|--|------------------|-----|------|

### **Electrical Characteristics**

(Ta=25°C unless otherwise specified)

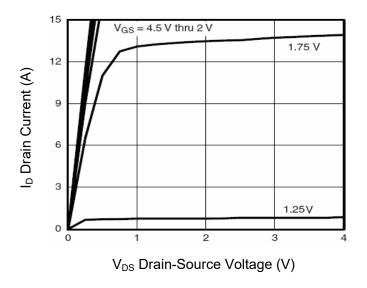
| Parameter                          | Symbol                 | Test Condition  | Min. | Тур. | Max. | Unit |
|------------------------------------|------------------------|---|------|------|------|------|
| Static Characteristics             | Static Characteristics |   |      |      |      |      |
| Drain-Source Breakdown Voltage     | V <sub>(BR)DSS</sub>   | V <sub>GS</sub> =0V,I <sub>D</sub> =250μA                           | 20   |      |      | V    |
| Zero Gate Voltage Drain Current    | I <sub>DSS</sub>       | V <sub>DS</sub> =20V,V <sub>GS</sub> =0V                            |      |      | 1    | μA   |
| Gate-Body Leakage Current          | I <sub>GSS</sub>       | V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V                           |      |      | ±100 | nA   |
| Gate Threshold Voltage Note3       | V <sub>GS(th)</sub>    | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA             | 0.5  | 0.7  | 1.2  | V    |
| D i Q D i ( Note?                  | D                      | V <sub>GS</sub> =4.5V,I <sub>D</sub> =6A                            |      |      | 28   | mΩ   |
| Drain-Source On-Resistance Note3   | R <sub>DS(on)</sub>    | V <sub>GS</sub> =2.5V,I <sub>D</sub> =5.5A                          |      |      | 35   | mΩ   |
| Forward Transconductance Note3     | <b>g</b> FS            | V <sub>DS</sub> =15V,I <sub>D</sub> =5A                             |      | 25   |      | S    |
| Dynamic Characteristics            |                        |   |      |      |      |      |
| Input Capacitance                  | C <sub>iss</sub>       | V <sub>DS</sub> =8V,V <sub>GS</sub> =0V,f=1MHz                      |      | 500  |      | pF   |
| Output Capacitance                 | Coss                   |   |      | 295  |      | pF   |
| Reverse Transfer Capacitance       | C <sub>rss</sub>       |   |      | 96   |      | pF   |
| Switching Characteristics          |                        |   |      |      |      |      |
| Turn-on Delay Time                 | t <sub>d(on)</sub>     | $V_{DD}$ =10V, $I_{D}$ =1A<br>$V_{GS}$ =4.5V, $R_{GEN}$ =6 $\Omega$ |      | 11   |      | nS   |
| Turn-on Rise Time                  | t <sub>r</sub>         |   |      | 30   |      | nS   |
| Turn-off Delay Time                | t <sub>d(off)</sub>    |   |      | 35   |      | nS   |
| Turn-off Fall Time                 | t <sub>f</sub>         |   |      | 10   |      | nS   |
| Total Gate Charge                  | Qg                     | V <sub>DS</sub> =10V,I <sub>D</sub> =3A,V <sub>GS</sub> =4.5V       |      | 10   |      | nC   |
| Gate-Source Charge                 | Q <sub>gs</sub>        |   |      | 2.3  |      | nC   |
| Gate-Drain Charge                  | $Q_{gd}$               |   |      | 2.9  |      | nC   |
| Source-Drain Diode Characteristics |                        |   |      |      |      |      |
| Diode Forward Voltage Note3        | V <sub>SD</sub>        | V <sub>GS</sub> =0V,I <sub>S</sub> =6.5A                            |      |      | 1.2  | V    |
| Diode Forward Current Note2        | Is                     |   |      |      | 6.5  | Α    |

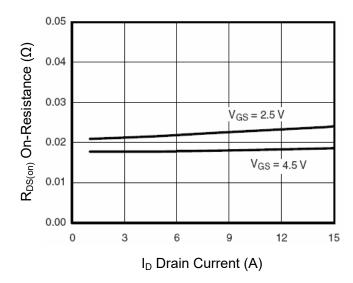
Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

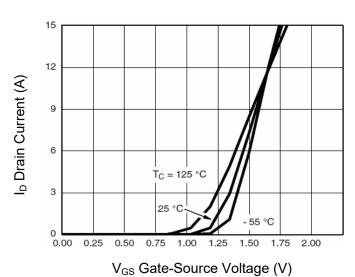
2. Surface Mounted on FR4 Board, t ≤ 10 sec.

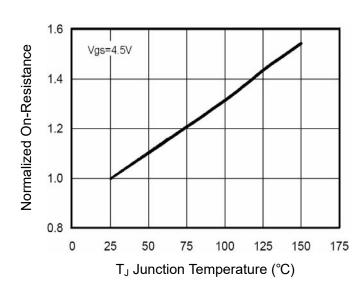
<sup>3.</sup> Pulse Test: Pulse width≤300µs, duty cycle≤2%.

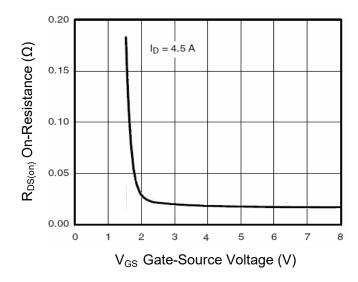
### **Typical Characteristic Curves**

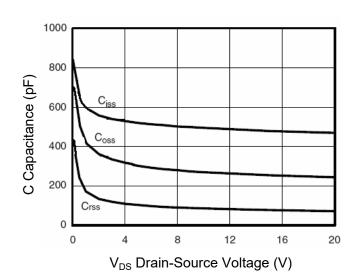


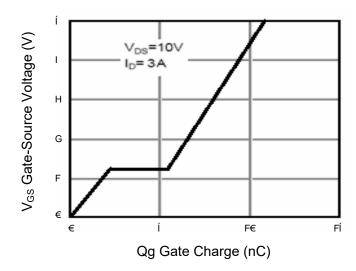


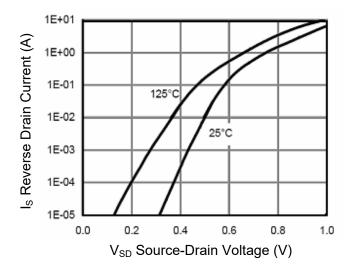


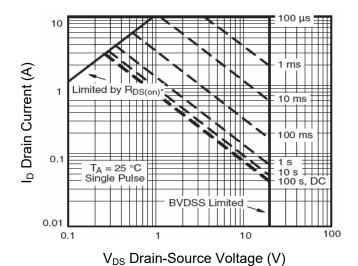












D=0.5

D=

10-2

Square Wave Pluse Duration(sec)

10-1

10<sup>0</sup>

10<sup>1</sup>

10<sup>2</sup>

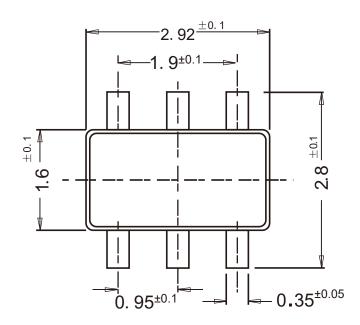
10-4

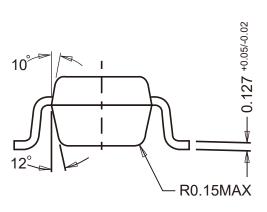
10-3

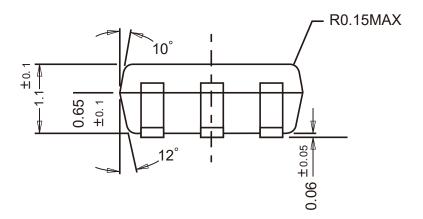
# **Package Outline**

SOT-23-6

Dimensions in mm





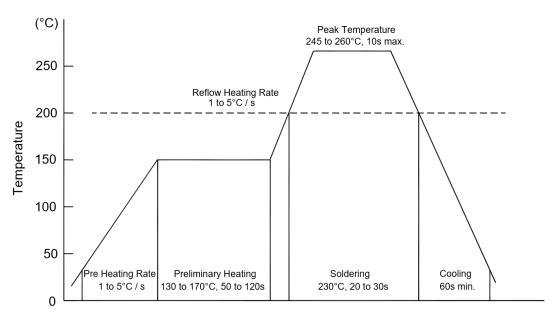


# **Ordering Information**

| Device     | Package  | Shipping              |
|------------|----------|-----------------------|
| TN2007DNSG | SOT-23-6 | 3,000PCS/Reel&7inches |

### **Conditions of Soldering and Storage**

#### Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

#### ♦ Conditions of hand soldering

Temperature: 370 °C

Time: 3s max.Times: one time

#### Storage conditions

Temperature

5 to 40 °C

Humidity

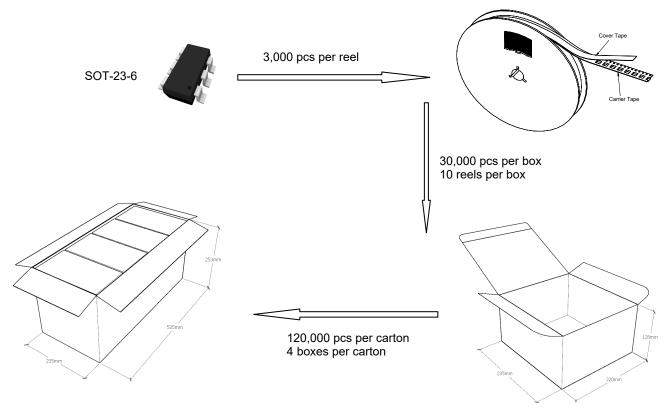
30 to 80% RH

Recommended period

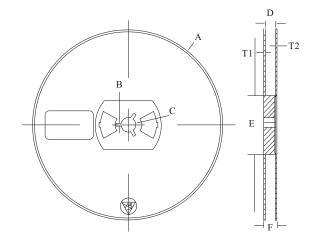
One year after manufacturing

### **Package Specifications**

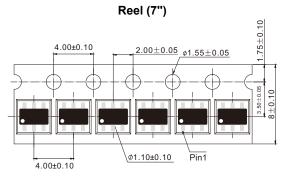
The method of packaging



### ♦ Embossed tape and reel data



| Symbol | Value (unit: mm) |  |
|--------|------------------|--|
| Α      | Ø 177.8±1        |  |
| В      | 2.7±0.2          |  |
| С      | Ø 13.5±0.2       |  |
| E      | Ø 54.5±0.2       |  |
| F      | 12.3±0.3         |  |
| D      | 9.6+2/-0.3       |  |
| T1     | 1.0±0.2          |  |
| T2     | 1.2±0.2          |  |



Tape (8mm)

#### **Contact Information**

TANI website: http://www.tanisemi.com Email:tani@tanisemi.com

For additional information, please contact your local Sales Representative.



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#### **Product Specification Statement**

The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up -to- date information to the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

TANI reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with TANI to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult TANI in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. TANI shall assume no responsibility for any consequences resulting from such usage.

Users should also comply with relevant laws, regulations, policies, and standards when using the product specification. Users are responsible for the risks and liabilities arising from the use of the product specification and must ensure that it is not used for illegal purposes. Additionally, users should respect the intellectual property rights related to the product specification and refrain from infringing upon any third- party legal rights. TANI shall assume no responsibility for any disputes or controv ersies arising from the above-mentioned issues in any form.